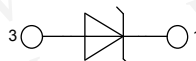


Schottky Diode

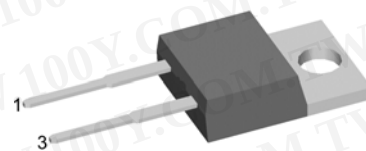
High Performance Schottky Diode
Low Loss and Soft Recovery
Common Cathode

Part number

DSB 20 I 15 PA



$$\begin{aligned} V_{RRM} &= 15 \text{ V} \\ I_{FAV} &= 20 \text{ A} \\ V_F &= 0.39 \text{ V} \end{aligned}$$



Backside: cathode

Features / Advantages:

- Very low V_f
- Extremely low switching losses
- low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package:

- Housing: TO-220
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

Ratings

Symbol	Definition	Conditions	min.	typ.	max.	Unit
V_{RRM}	max. repetitive reverse voltage	$T_{VJ} = 25^\circ\text{C}$			15	V
I_R	reverse current	$V_R = 15\text{V}$ $T_{VJ} = 25^\circ\text{C}$			10	μA
		$V_R = 15\text{V}$ $T_{VJ} = 100^\circ\text{C}$			40	mA
V_F	forward voltage	$I_F = 20\text{A}$ $T_{VJ} = 25^\circ\text{C}$			0.48	V
		$I_F = 40\text{A}$			0.60	V
		$I_F = 20\text{A}$ $T_{VJ} = 125^\circ\text{C}$			0.39	V
		$I_F = 40\text{A}$			0.54	V
I_{FAV}	average forward current	rectangular, $d = 0.5$ $T_C = 130^\circ\text{C}$			20	A
V_{F0}	threshold voltage	$T_{VJ} = 150^\circ\text{C}$ for power loss calculation only			0.23	V
r_F	slope resistance				7.2	$\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				1.75	K/W
T_{VJ}	virtual junction temperature		-55		150	$^\circ\text{C}$
P_{tot}	total power dissipation	$T_C = 25^\circ\text{C}$			70	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}$ (50 Hz), sine $T_{VJ} = 45^\circ\text{C}$			160	A
C_J	junction capacitance	$V_R = \text{tbd V}$; $f = 1 \text{ MHz}$ $T_{VJ} = 25^\circ\text{C}$		tbd		pF

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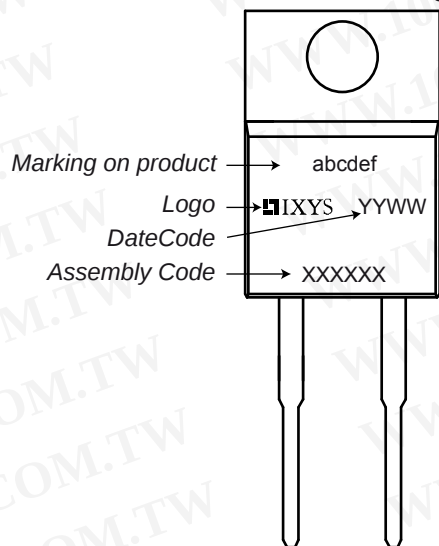
Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	Unit
I_{RMS}	RMS current	per pin ¹⁾			35	A
R_{thCH}	thermal resistance case to heatsink			0.50		K/W
T_{stg}	storage temperature		-55		150	°C
Weight				2		g
M_D	mounting torque		0.4		0.8	Nm
F_c	mounting force with clip		20		60	N

¹⁾ I_{RMS} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

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Product Marking



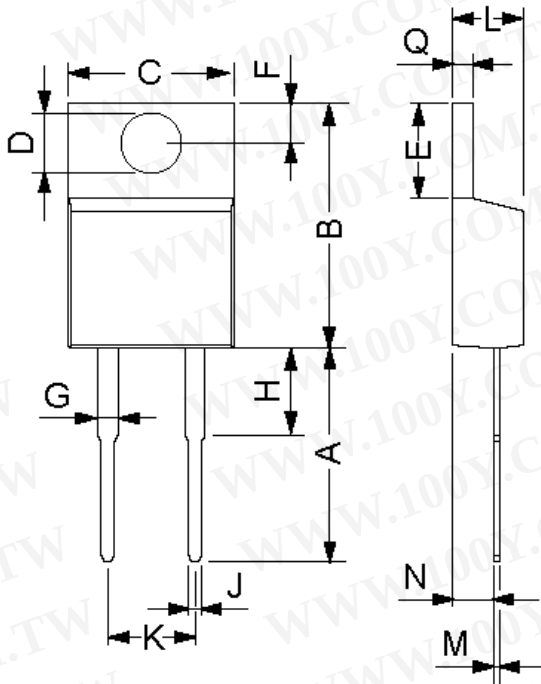
Part number

D = Diode
 S = Schottky Diode
 B = ultra low VF
 20 = Current Rating [A]
 I = Common Cathode
 15 = Reverse Voltage [V]
 PA = TO-220AC (2)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSB 20 I 15 PA	DSB20I15PA	Tube		

Package

Outlines TO-220



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.7	14.73	0.5	0.58
B	14.23	16.51	0.56	0.65
C	9.66	10.66	0.38	0.42
D	3.54	4.08	0.139	0.161
E	5.85	6.85	2.3	0.42
F	2.54	3.42	0.1	0.135
G	1.15	1.77	0.045	0.07
H	-	6.35	-	0.25
J	0.64	0.89	0.025	0.035
K	4.83	5.33	0.19	0.21
L	3.56	4.82	0.14	0.19
M	0.51	0.76	0.02	0.03
N	2.04	2.49	0.08	0.115
Q	0.64	1.39	0.025	0.055

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